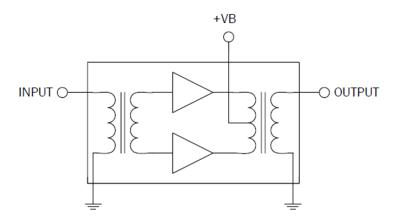


D10040300GTH

GaAs Power Doubler Hybrid 40MHz to 1GHz

The D10040300GTH is a Hybrid Power Doubler amplifier module with high output capability. The D10040300GTH employs GaAs dice and is operated from 40MHz to 1000MHz. The part provides excellent linearity and superior return loss performance with low noise and optimal reliability.



Ordering Information

D10040300GTH Box with 50 pieces

Absolute Maximum Ratings

Parameter	Rating	Unit
RF Input Voltage (single tone)	75	dBmV
DC Supply Over-Voltage (5 minutes)	30	V
Storage Temperature	-40 to +100	°C
Operating Mounting Base Temperature	-30 to +100	°C



Package: SOT-115J

Features

- Excellent Linearity
- Superior Return Loss Performance
- Extremely Low Distortion
- Optimal Reliability
- Low Noise
- Unconditionally Stable Under All Terminations
- 30.5dB Min. Gain at 1000MHz
- 440mA Max. at 24VDC

Applications

40MHz to 1000MHz CATV Amplifier Systems



Caution! ESD sensitive device.



RoHS (Restriction of Hazardous Substances): Compliant per EU Directive 2011/65/EU.

Exceeding any one or a combination of the Absolute Maximum Rating conditions may cause permanent damage to the device. Extended application of Absolute Maximum Rating conditions to the device may reduce device reliability. Specified typical performance or functional operation of the device under Absolute Maximum Rating conditions is not implied.



Nominal Operating Parameters

Davamatan	Specification		Unit	O and this are		
Parameter		Тур	Max	Unit	Condition	
General Performance					$V+ = 24V; T_{MB} = 30^{\circ}C; Z_{S} = Z_{L} = 75\Omega$	
Power Gain	29.5	30.0	30.5	dB	f = 50MHz	
	30.5		32.0	dB	f = 1000MHz	
Slope ^[1]	0.5		2.0	dB	f = 40MHz to 1000MHz	
Flatness of Frequency Response			0.8	dB	f = 40MHz to 1000MHz (Peak to Valley)	
	20.0			dB	f = 40MHz to 320MHz	
Input Return Loss	19.0			dB	f = 320MHz to 640MHz	
	17.0			dB	f = 640MHz to 870MHz	
	16.0			dB	f = 870MHz to 1000MHz	
Output Return Loss	20.0			dB	f = 40MHz to 320MHz	
	19.0			dB	f = 320MHz to 640MHz	
	18.0			dB	f = 640MHz to 870MHz	
	17.0			dB	f = 870MHz to 1000MHz	
Noise Figure		3.5	4.5	dB	f = 50MHz to 1000MHz	
Total Current Consumption (DC)		420.0	440.0	mA		
Distortion Data 40MHz to 550MHz					$V+ = 24V; T_{MB} = 30^{\circ}C; Z_{S} = Z_{L} = 75\Omega$	
СТВ		-65	-63	dBc		
XMOD		-62	-60	dBc	79ch. 7dB tilted, V_o = 52dBmV at 550MHz ^[2]	
CSO		-65	-63	dBc		

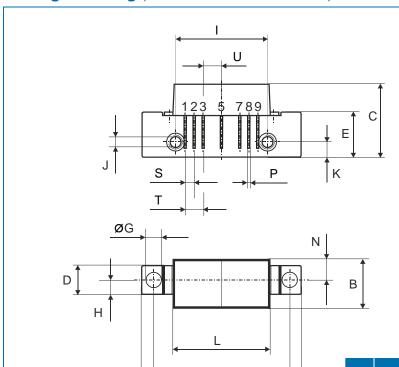
^{1.} The slope is defined as the difference between the gain at the start frequency and the gain at the stop frequency.

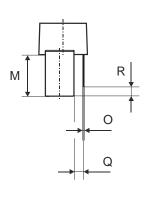
Cross Modulation (XMOD) - Cross modulation (XMOD) is measured at baseband (selective voltmeter method), referenced to 100% modulation of the carrier being tested.

^{2. 79} channels, NTSC frequency raster: 55.25MHz to 547.25MHz, +45dBmV to +52dBmV tilted output level. Composite Second Order (CSO) - The CSO parameter (both sum and difference products) is defined by the NCTA. Composite Triple Beat (CTB) - The CTB parameter is defined by the NCTA.



Package Drawing (Dimensions in millimeters)





0 5 10mm لسلسا scale

Notes:

European Projection





Pinning:

Pin	Name
1	Input
2-3	GND
4	
5	+VB
6	
7-8	GND
9	Output

	Nominal	Min	Max
Α	44,6 ^{± 0,2}	44,4	44,8
В	13,6 ^{± 0,2}	13,4	13,8
С	20,4 ^{± 0,5}	19,9	20,9
D	8 ^{± 0,15}	7,85	8,15
Ε	12,6 ^{± 0,15}	12,45	12,75
F	38,1 ^{± 0,2}	37,9	38,3
G	4 +0,2 / -0,05	3,95	4,2
Н	4 ^{± 0,2}	3,8	4,2
1	25,4 ^{± 0,2}	25,2	25,6
J	UNC 6-32	-	-
K	4,2 ^{± 0,2}	4,0	4,4
L	27,2 ^{± 0,2}	27,0	27,4
М	11,6 ^{± 0,5}	11,1	12,1
N	5,8 ^{± 0,4}	5,4	6,2
0	0,25 ^{± 0,02}	0,23	0,27
Р	0,45 ^{± 0,03}	0,42	0,48
Q	2,54 ^{± 0,3}	2,24	2,84
R	2,54 ^{± 0,5}	2,04	3,04
S	2,54 ^{± 0,25}	2,29	2,79
Т	5,08 ^{± 0,25}	4,83	5,33
U	5,08 ^{± 0,25}	4,83	5,33